NSN 5961-01-111-7438

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-111-7438 **Inclosure Material:** Metal **Overall Length:** 0.405 inches **Overall Diameter:** 0.338 inches **Mounting Facility Quantity:** Joint Electronic Device Engineering Council/jedec/case Outline Designation: D0-4 **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** 0.433 inches **Thread Size:** 0.190 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 20.0 repetitive peak reverse voltage and 24.0 nonrepetitive peak reverse voltage and 20.0 reverse voltage, dc **Current Rating Per Characteristic:** 20.00 amperes source cutoff current preset **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius junction **Thread Series Designator:** Unf **Terminal Type And Quantity:** 1 threaded stud and 1 tab, solder lug Shelf Life: N/a **Unit Of Measure: Demilitarization:** No

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